74AHCT1G125

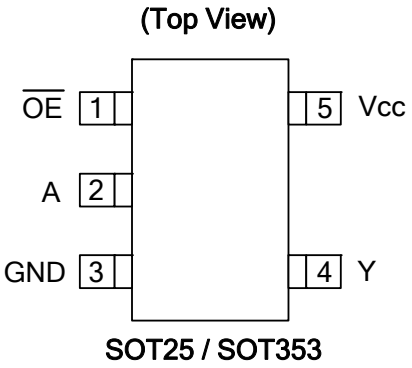
SINGLE BUFFER GATE WITH 3-STATE OUTPUT

NEW PRODUCT

Description

The 74AHCT1G125 is a single non-inverting buffer/bus driver with a 3-state output. The output enters a high impedance state when a HIGH-level is applied to the output enable ($\overline{OE}$) pin. The device is designed for operation with a power supply range of 4.5V to 5.5V.

Pin Assignments



Features

- Supply Voltage Range from 4.5V to 5.5V
- ± 8 mA Output Drive at 5.0V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time.
- ESD Protection per JESD 22
  - Exceeds 200-V Machine Model (A115-A)
  - Exceeds 2000-V Human Body Model (A114-A)
  - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- SOT25 and SOT353: Assembled with “Green” Molding Compound (no Br, Sb)
- Lead Free Finish / RoHS Compliant (Note 1)

Applications

- General Purpose Logic
- Wide array of products such as:
  - PCs, networking, notebooks, netbooks, PDAs
  - Computer peripherals, hard drives, CD/DVD ROM
  - TV, DVD, DVR, set top box
  - Phones, Personal Navigation / GPS
  - MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.

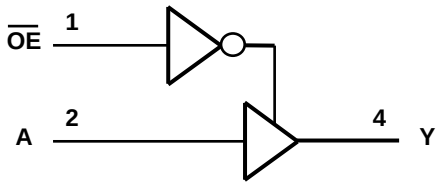
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Pin Descriptions

Pin Name	Pin No.	Description
$\overline{OE}$	1	Output Enable
A	2	Data Input
GND	3	Ground
Y	4	Data Output
V_{CC}	5	Supply Voltage

Logic Diagram



Function Table

Inputs		Output
$\overline{OE}$	A	Y
L	H	H
L	L	L
H	X	Z

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Absolute Maximum Ratings (Note 2)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V_{CC}	Supply Voltage Range	-0.5 to 6.5	V
V_I	Input Voltage Range	-0.5 to 6.5	V
V_O	Voltage applied to output in high or low state	-0.5 to V_{CC} +0.5	V
I_{IK}	Input Clamp Current V_I<0	-20	mA
I_{OK}	Output Clamp Current (V_O < 0 or V_O > V_{CC})	±20	mA
I_O	Continuous output current (V_O = 0 to V_{CC})	±25	mA
I_{CC}	Continuous current through V_{CC}	50	mA
I_{GND}	Continuous current through GND	-50	mA
T_J	Operating Junction Temperature	-40 to 150	°C
T_{STG}	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Unit
V_{CC}	Operating Voltage		4.5	5.5	V
V_{IH}	High-level Input Voltage		2.0		V
V_{IL}	Low-level input voltage			0.8	V
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage		0	V_{CC}	V
I_{OH}	High-level output current			-8	mA
I_{OL}	Low-level output current			8	mA
Δt/ΔV	Input transition rise or fall rate			20	ns/V
T_A	Operating free-air temperature		-40	125	ºC

Notes: 3. Unused inputs should be held at V_{CC} or Ground.

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Electrical Characteristics

Symbol	Parameter	Test Conditions	V_{CC}	25ºC			-40ºC to 85ºC		-40ºC to 125ºC		Unit
				Min	Typ.	Max	Min	Max	Min	Max	
V_{OH}	High Level Output Voltage	I_{OH} = -50µA	4.5V	4.4	4.5		4.4		4.4		V
		I_{OH} = -8mA	4.5V	3.94			3.8		3.70		
V_{OL}	Low Level Output Voltage	I_{OL} = 50µA	4.5V		0	0.1		0.1		0.1	V
		I_{OL} = 8mA	4.5V			0.36		0.44		0.55	
I_I	Input Current	V_I = 5.5V or GND	0 to 5.5V			±0.1		±1		±2	µA
I_{OZ}	Z State Leakage Current	V_O =0 to 5.5V	5.5V			0.25		2.5		10	µA
I_{CC}	Supply Current	V_I = 5.5V or GND I_O=0	5.5V			1		10		40	µA
C_i	Input Capacitance	V_I = V_{CC} – or GND	5.5V		2.0	10		10		10	pF
ΔI_{CC}	Additional Supply Current	One input at 3.4 V Other inputs at V_{CC} or GND	5.5V			1.35		1.5			mA
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOT25	(Note 4)		204						°C/W
		SOT353			371						
θ_{JC}	Thermal Resistance Junction-to-Case	SOT25	(Note 4)		52						°C/W
		SOT353			143						

Note: 4. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

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Switching Characteristics

V_{CC} = 5V ± 0.5V (see Figure 1)

Parameter	From (Input)	TO (OUTPUT)		25ºC			-40ºC to 85ºC		-40ºC to 125ºC		Unit
				Min	Typ.	Max	Min	Max	Min	Max	
t_{pd}	A	Y	C_L=15pF	0.6	3.4	5.5	0.6	6.5	0.6	7.0	ns
			C_L=50pF	0.6	4.7	7.5	0.6	8.5	0.6	9.5	ns
t_{en}	$\overline{OE}$	Y	C_L=15pF	0.6	3.6	5.6	0.6	6.3	0.6	7.0	ns
			C_L=50pF	0.6	5.4	8.0	0.6	9.0	0.6	9.5	ns
t_{dis}	$\overline{OE}$	Y	C_L=15pF	0.6	4.3	6.8	0.6	8.0	0.6	8.5	ns
			C_L=50pF	0.6	6.1	8.8	0.6	10.0	0.6	11.0	ns

Operating Characteristics

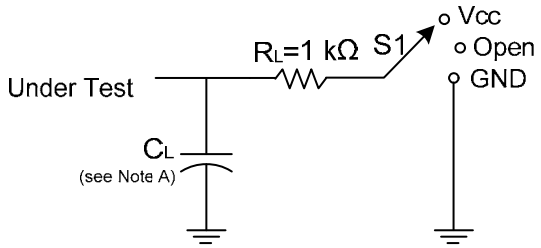
T_A = 25 ºC

Parameter		Test Conditions	V_{CC} = 5 V	Unit
			Typ.	
C_{pd}	Power dissipation capacitance	f = 1 MHz No Load	14	pF

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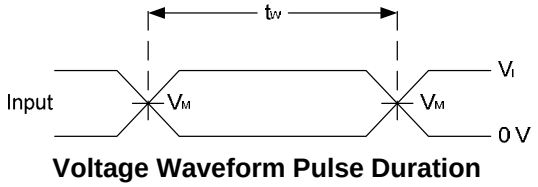
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Parameter Measurement Information

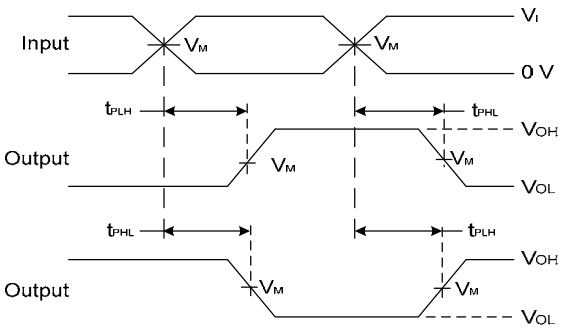


TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	Vload
t_{PHZ}/t_{PZH}	GND

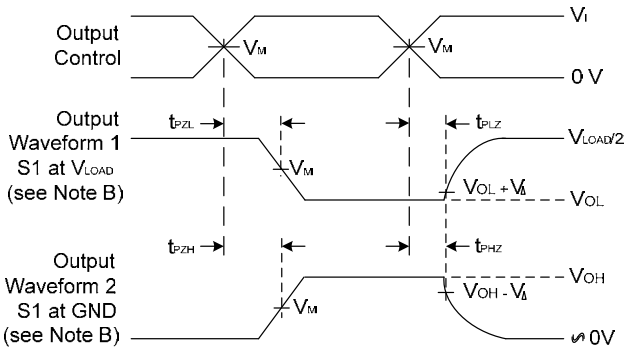
Vcc	Inputs		V_M	C_L	VΔ
	V_I	t_r/t_f			
5V±0.5V	V_{CC}	≤3ns	$V_{CC}/2$	15pF	0.3V
5V±0.5V	V_{CC}	≤3ns	$V_{CC}/2$	50pF	0.3V



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times Low and High Level Enabling

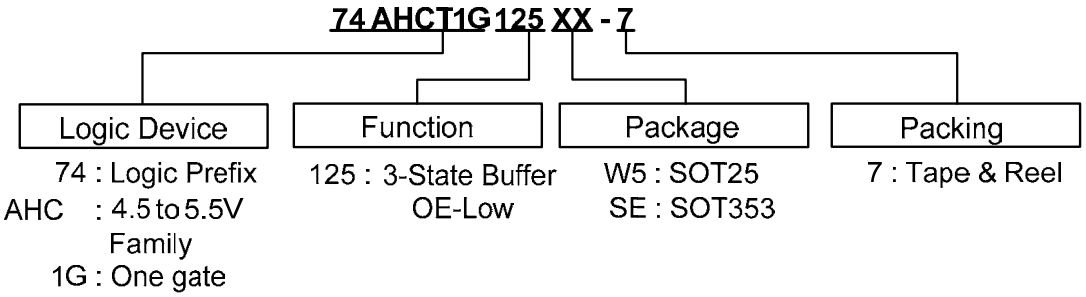
Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.
B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
C. Inputs are measured separately one transition per measurement.
D. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
E. t_{PZL} and t_{PZH} are the same as t_{EN}.
F. t_{PLH} and t_{PHL} are the same as t_{PD}.

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Ordering Information

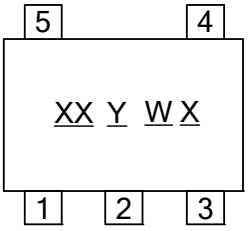


Device	Package Code	Packaging (Note 5)	7" Tape and Reel	
			Quantity	Part Number Suffix
74AHCT1G125W5-7	W5	SOT25	3000/Tape & Reel	-7
74AHCT1G125SE-7	SE	SOT353	3000/Tape & Reel	-7

Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

Marking Information

(Top View)



XX : Identification code
Y : Year 0~9
W : Week : A~Z : 1~26 week;
a~z : 27~52 week; z represents 52 and 53 week
X : A~Z : Internal code

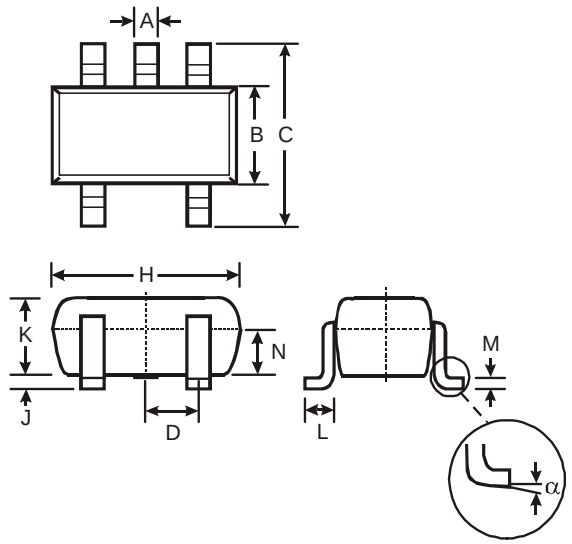
Part Number	Package	Identification Code
74AHCT1G125W5	SOT25	ZY
74AHCT1G125SE	SOT353	ZY

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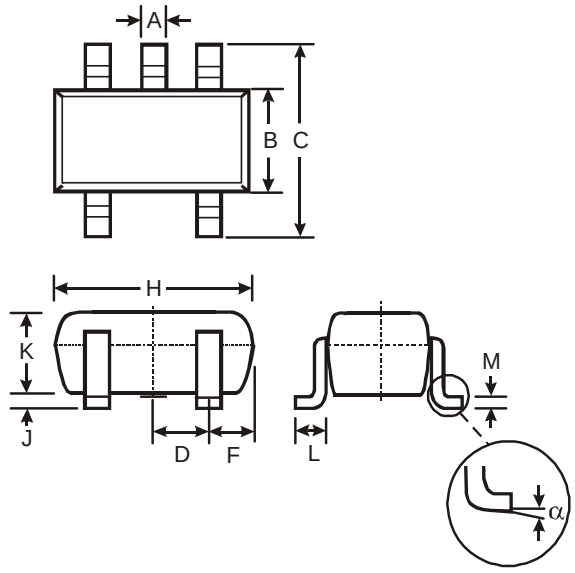
Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



SOT25			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	—
All Dimensions in mm			

(2) Package Type: SOT353



SOT353		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Typ	
F	0.40	0.45
H	1.80	2.20
J	0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.22
α	0°	8°
All Dimensions in mm		

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